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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



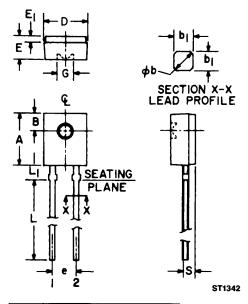






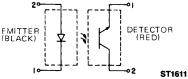
## H23A1/2

### PACKAGE DIMENSIONS



SYMBOL	MILLIM	ETERS	INCHES		NOTES
01111002	MIN.	MAX.	MIN.	MAX.	
Α	5.59	5.80	.220	.228	
В	1.78	NOM.	.070	NOM.	2
<b>®</b> b	.60	.75	.024	.030	1
b₁	.51	NOM.	.020	NOM.	1
D	4.45	4.70	.175	.185	
Е	2.41	2.67	.095	.105	
E,	.58	.69	.023	.027	
е	2.41	2.67	.095	.105	3
G	1.98	NOM.	.078	NOM.	
L	12.7	_	.500		
L,	1.40	1.65	.055	.065	
S	.83	.94	.033	.037	3

### **PACKAGE OUTLINE**



#### NOTES

- 1. TWO LEADS. LEAD CROSS SECTION DIMENSIONS UNCONTROLLED WITHIN 1.27 mm (0.50") OF SEATING PLANE.
- 2. CENTERLINE OF ACTIVE ELEMENT LOCATED WITHIN .25 mm (.010") OF TRUE POSITION.
- 3. AS MEASURED AT THE SEATING PLANE.
- 4. INCH DIMENSIONS DERIVED FROM MILLIMETERS.

### DESCRIPTION

The H23A is a matched emitter-detector pair which consists of a gallium arsenide infrared emitting diode and a silicon phototransistor. The clear epoxy packaging system is designed to optimize the mechanical resolution, coupling efficiency, cost, and reliability. The devices are marked with a color dot for easy identification of the emitter and detector.

### FEATURES

- Good optical to mechanical alignment
- Color dot for easy recognition of LED and phototransistor
- Low cost



Storage Temperature	55°C to +100°C
Operating Temperature	55°C to +100°C
Soldering:  Lead Temperature (Iron)	
INPUT DIODE	
Continuous Forward Current	
Forward Current (pw, 1 $\mu$ S; 33 Hz)	3 A
Reverse Voltage	
Power Dissipation	
OUTPUT TRANSISTOR	
Collector-Emitter Voltage	30 Volts
Emitter-Collector Voltage	6 Volts
Power Dissipation	

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
INPUT DIODE						
Forward Voltage	$V_{\scriptscriptstyle F}$			1.7	٧	$I_{\rm F}=60~{\rm mA}$
Reverse Leakage Current	l <sub>e</sub>	_		10	μΑ	$V_R = 6V$
Reverse Breakdown Voltage	BV <sub>R</sub>	6.0			٧	$I_R = 10\mu A$
OUTPUT TRANSISTOR						
Emitter-Collector Breakdown	$BV_{ECO}$	6.0		_	٧	$I_{\scriptscriptstyle E}=100\mu A$
Collector-Emitter Breakdown	BV <sub>CEO</sub>	30		_	٧	$I_c = 10 \text{ mA}$
Collector-Emitter Leakage	I <sub>CEO</sub>	_		100	nA	V <sub>CE</sub> = 10 V
COUPLED					***	
On-State Collector Current	( <sub>C(ON)</sub>		See page 3.			
Saturation Voltage	V <sub>CE(SAT)</sub>		See page 3.			
Turn-On Time	t <sub>on</sub>		150		μS	I <sub>F</sub> =30 mA, V <sub>cc</sub> =5V R <sub>L</sub> =2.5KΩ
Turn-Off Time	t <sub>off</sub>		150		μS	$I_{\rm F}$ =30 mA, $V_{\rm GG}$ =5V R <sub>I</sub> =2.5K $\Omega$

#### NOTES

- Derate power dissipation linearly 1.33mW/°C above 25°C.
   Derate power dissipation linearly 2.00mW/°C above 25°C.
- 3. RMA flux is recommended.

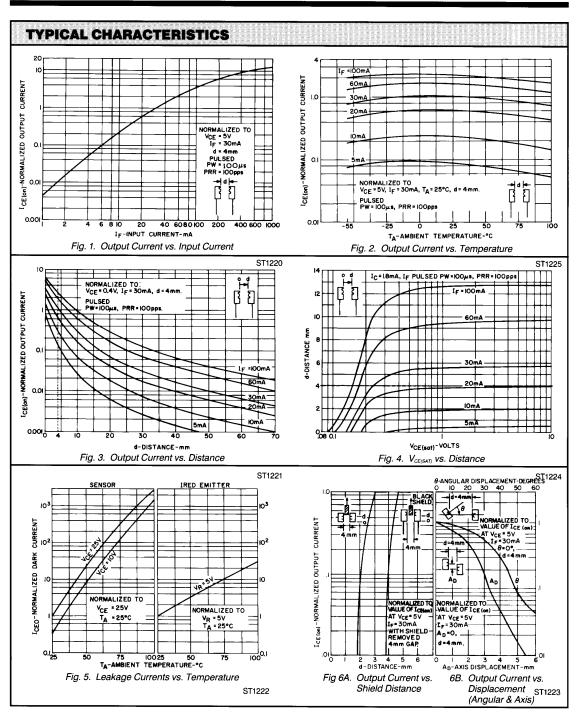
- Methanol or Isopropyl alcohols are recommended as cleaning agents.
   Soldering iron tip 1/6" (1.6 mm) minimum from housing.
   Coupled characteristics are measured at a separation distance of .155" (4 mm) with the lenses of the emitter and detector on a common axis within 0.1mm and parallel within 5°.



# H23A1/2

I <sub>C(ON)</sub> and V <sub>CE(SA</sub>	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
ON-STATE COLLEC	TOR CURRENT	•				-14.6
H23A1	I <sub>C(ON)</sub>	1.5			mA	$I_F = 30 \text{mA}, V_{CE} = 5 V^{(6)}$
H23A2	I <sub>C(ON)</sub>	0.5			mA	$I_{\rm F} = 30 {\rm mA}, V_{\rm CE} = 5 {\rm V}^{(6)}$
ATURATION VOLT	AGE					
H23A1	$V_{CE(SAT)}$	_	_	0.40	V	$I_F = 30 \text{mA}, I_C = 1.0 \text{mA}$
H23A2	V <sub>CE(SAT)</sub>	_		0.40	V	$I_F = 30 \text{mA}, I_C = .4 \text{mA}^{(6)}$







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